



A Product Line of Diodes Incorporated



DXT2010P5

$\begin{array}{l} \textbf{60V NPN MEDIUM POWER TRANSISTOR} \\ \textbf{PowerDI}^{\$}\textbf{5} \end{array}$

Features

- 43% smaller than SOT223; 60% smaller than TO252
- Maximum height just 1.1mm
- Rated up to 3.2W
- V_{CEO} = 60V
- I_C = 6A; I_{CM} = 20A
- Low Saturation voltage
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Applications

- Motor driver
- Regulator circuit

Mechanical Data

- Case: PowerDI[®]5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @:
- Weight: 0.093 grams (approximate)

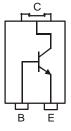


Top View

Bottom View



С



Device Schematic

Pin-out diagram

Ordering Information (Note 3)

Part Number	Case	Packaging	
DXT2010P5-13	PowerDI [®] 5	5000/Tape & Reel	

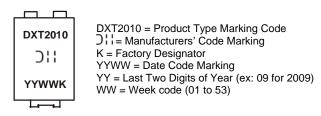
В

Notes: 1. No purposefully added lead. Halogen and Antimony Free.

2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

3. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information







Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	150	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	lc	6	А
Peak Pulse Current	I _{CM}	20	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ $T_A = 25^{\circ}C$ (Note 4)	PD	3.2	W
Thermal Resistance, Junction to Ambient Air (Note 4) $@T_A = 25^{\circ}C$	R _{0JA}	39	°C/W
Power Dissipation @ $T_A = 25^{\circ}C$ (Note 5)	PD	1.7	W
Thermal Resistance, Junction to Ambient Air (Note 5) $@T_A = 25^{\circ}C$	R _{0JA}	75	°C/W
Power Dissipation @ $T_A = 25^{\circ}C$ (Note 6)	PD	0.74	W
Thermal Resistance, Junction to Ambient Air (Note 6) $@T_A = 25^{\circ}C$	$R_{ ext{ heta}JA}$	169	°C/W
Thermal Resistance, Junction to Collector Terminal	R _{0JT}	5.6	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

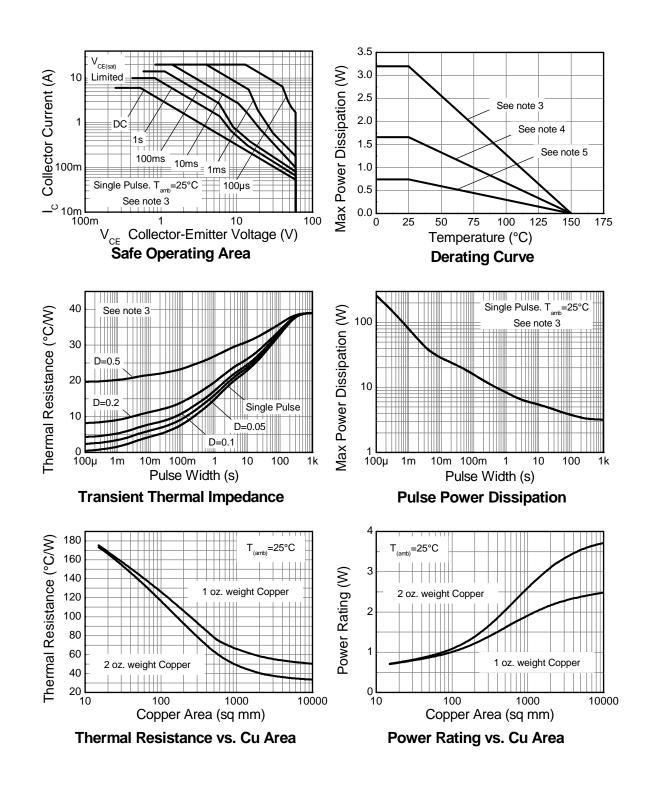
 Device mounted on FR-4 PCB, single sided 2 oz. copper, collector pad dimensions 25mm x 25mm.
Device mounted on FR-4 PCB, single sided 1 oz. copper, collector pad dimensions 50mm x 50mm.
Device mounted on FR-4 PCB, single sided 1 oz. copper, minimum recommended pad layout. Notes:



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Electrical Characteristics @T_A = 25°C unless otherwise specified

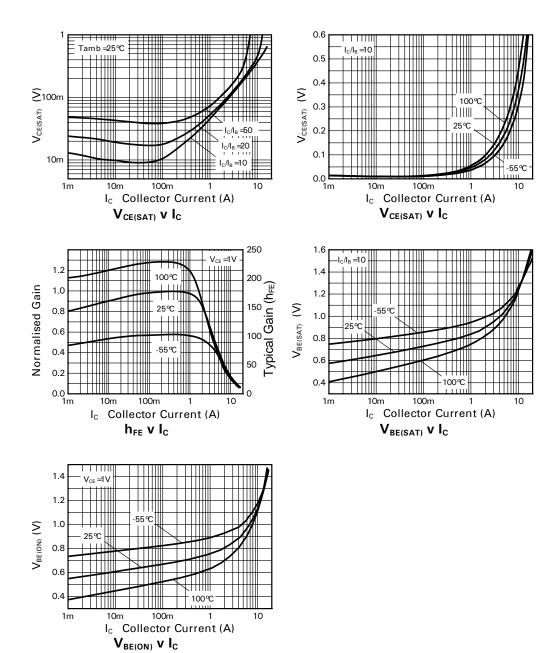
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	V _{(BR)CBO}	150	190		V	$I_{\rm C} = 100 \mu {\rm A}$
Collector-Emitter Breakdown Voltage (Note 7)	V _{(BR)CEO}	60	80	_	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	7.0	8.1		V	$I_E = 100 \mu A$
Collector Cutoff Current	I _{СВО}	_	_	20 0.5	nA μA	V _{CB} = 120V V _{CB} = 120V, T _{amb} = 100 °C
Collector Cutoff Current	l _{CER} R≤1kΩ	_	_	20 0.5	nA μA	V _{CB} = 120V V _{CB} = 120V, T _{amb} = 100 °C
Emitter Cutoff Current	I _{EBO}	_	_	10	nA	V _{EB} = 6V
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}		20 45 50 100 210	30 60 70 135 260	mV	$\begin{split} I_{C} &= 100 \text{mA}, \ I_{B} &= 5 \text{mA} \\ I_{C} &= 1 \text{A}, \ I_{B} &= 100 \text{mA} \\ I_{C} &= 1 \text{A}, \ I_{B} &= 50 \text{mA} \\ I_{C} &= 2 \text{A}, \ I_{B} &= 50 \text{mA} \\ I_{C} &= 6 \text{A}, \ I_{B} &= 300 \text{mA} \end{split}$
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	_	1000	1100	mV	$I_{\rm C} = 6A, I_{\rm B} = 300 {\rm mA}$
Base-Emitter Turn-On Voltage (Note 7)	V _{BE(on)}	_	940	1050	mV	$V_{CE} = 1V$, $I_C = 6A$
DC Current Gain (Note 6)	h _{FE}	100 100 55 20	200 200 105 40	 300 	_	$\begin{split} I_{C} &= 10 \text{mA}, \ V_{CE} = 1 \text{V} \\ I_{C} &= 2 \text{A}, \ V_{CE} = 1 \text{V} \\ I_{C} &= 5 \text{A}, \ V_{CE} = 1 \text{V} \\ I_{C} &= 10 \text{A}, \ V_{CE} = 1 \text{V} \end{split}$
Transition Frequency	f⊤	_	130	_	MHz	$I_{C} = 100 \text{mA}, V_{CE} = 10 \text{V}$ f = 50MHz
Output Capacitance (Note 7)	C _{obo}		31		pF	V _{CB} = -10A, f = 1MHz
Switching Times	t _{on} t _{off}		42 760		ns ns	$I_{C} = 1A, V_{CC} = 10V,$ $I_{B1} = I_{B2} = 100mA$

7. Pulse Test: Pulse width \leq 300µs. Duty cycle \leq 2.0%. Notes:





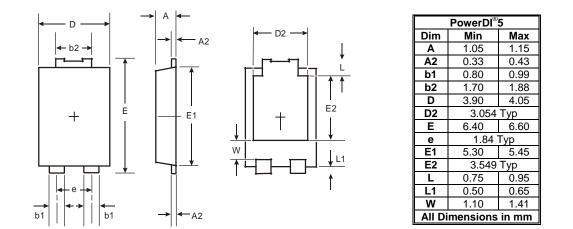
Typical Characteristic



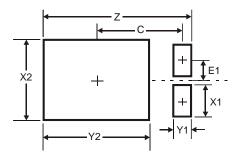




Package Outline Dimensions



Suggested Pad Layout



-	
Dimensions	Value (in mm)
Z	6.6
X1	1.4
X2	3.6
Y1	0.8
Y2	4.7
С	3.87
E1	0.9





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